

1. Description

The IRFL9014TRPBF(ES) is P-Channel enhancement MOS Field Effect Transistor. Uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. Device is suitable for use in DC-DC conversion, power switch and charging circuit. Standard Product IRFL9014TRPBF(ES) is Pb-free.

2. Features

- -60V, $R_{DS(ON)}=90m\Omega(Typ.) @V_{GS}=-10V$
- $R_{DS(ON)}=117m\Omega(Typ.) @V_{GS}=-4.5V$
- Fast Switching
- High density cell design for low $R_{DS(on)}$
- Material: Halogen free
- Reliable and rugged
- Avalanche Rated
- Low leakage current

3. Applications

- PWM applications
- Load switch
- Power management in portable/desktop PCs
- DC/DC conversion

4. Ordering Information

Part Number	Package	Marking	Material	Packaging	Quantity per reel	Flammability Rating	Reel Sizes
IRFL9014TRPBF(ES)	SOT-223	PG06R114/LO T	Halogen free	Tape & Reel	2,500 PCS	UL 94V-0	13 inches

Table-1 Ordering information

5. Pin Configuration and Functions

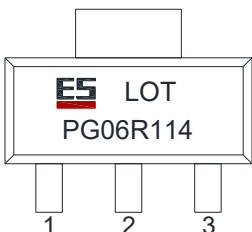
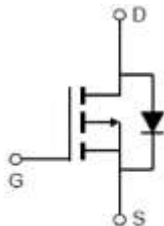
Pin	Function	Outline	Circuit Diagram
1	Gate		
3	Source		
2	Drain		

Table-2 Pin configuration

6. Specification

Absolute Maximum Rating & Thermal Characteristics

Ratings at 25 °C ambient temperature unless otherwise specified.

Parameter		Symbol	Limit	Unit
Drain-Source Voltage		BV_{DSS}	-60	V
Gate-Source Voltage		V_{GS}	±20	V
Continuous Drain Current	$T_A=25^{\circ}C$	I_D	-3.0	A
	$T_A=100^{\circ}C$		-1.8	
Maximum Power Dissipation	$T_A=25^{\circ}C$	P_D	1.6	W
Pulsed Drain Current		I_{DM}	-12	A
Operating Junction Temperature		T_J	-55 to +150	°C
Storage Temperature Range		T_{stg}	-55 to +150	°C

Thermal resistance ratings

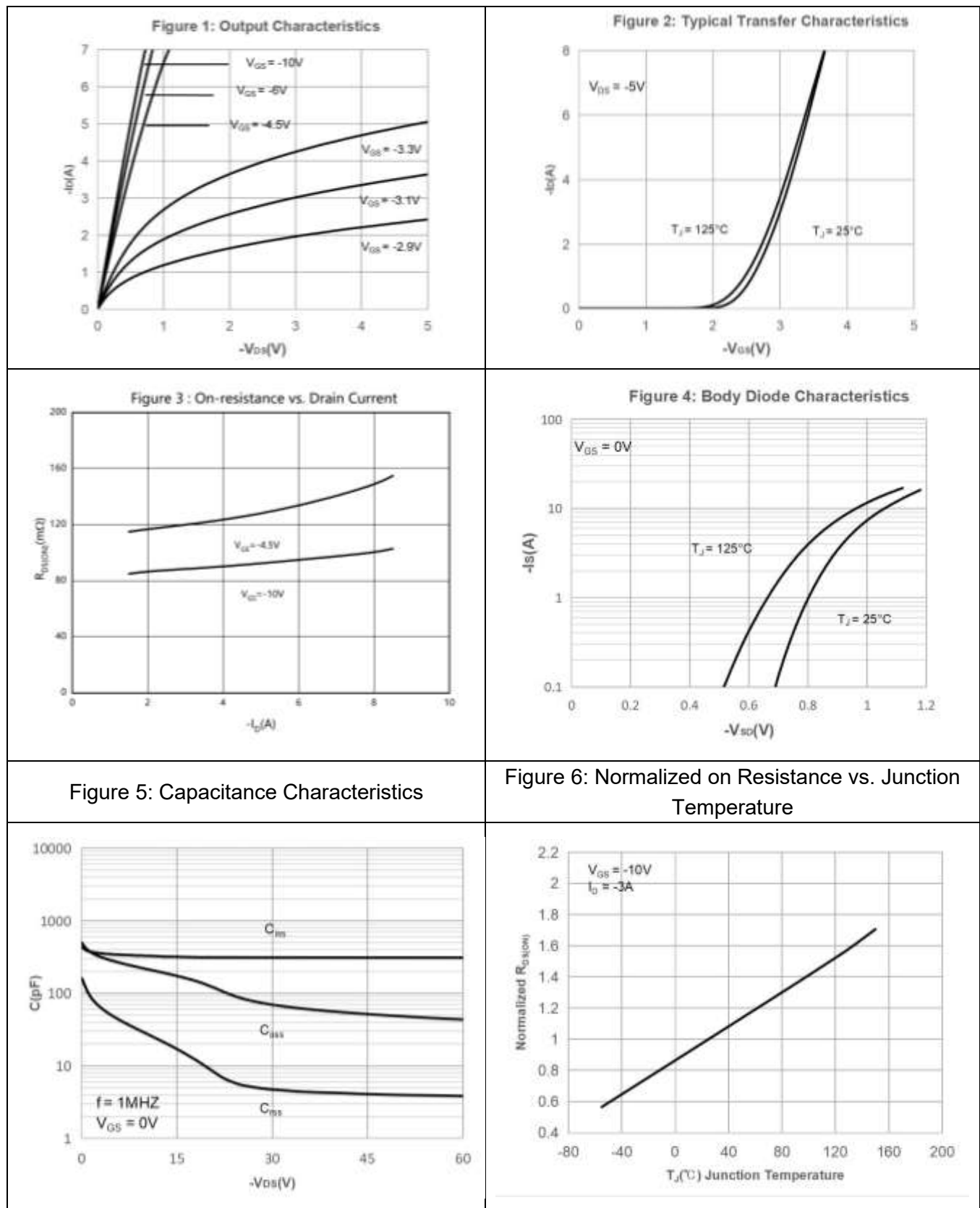
Parameter	Symbol	Maximum	Unit
Junction-to-Ambient Thermal Resistance	$R_{\theta JA}$	78	°C/W

Electrical Characteristics

At TA = 25°C unless otherwise specified

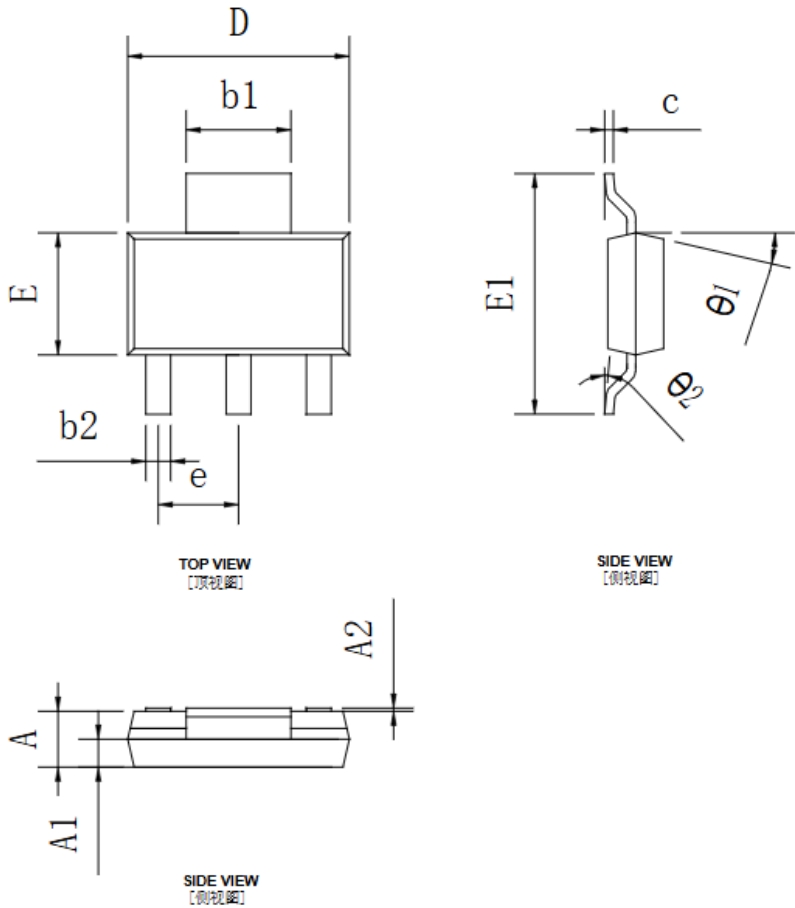
Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
OFF CHARACTERISTICS						
Drain-to-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =-250uA	-60			V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-60V, V _{GS} =0V			-1	uA
Gate-to-source Leakage Current	I _{GSS}	V _{DS} =0V, V _{GS} =±20V			±100	nA
ON CHARACTERISTICS						
Gate Threshold Voltage	V _{GS(TH)}	V _{GS} =V _{DS} , I _D =-250uA	-1.1	-1.8	-2.4	V
Drain-to-source On-resistance	R _{DS(on)}	V _{GS} =-10V, I _D =-3A		90	114	mΩ
		V _{GS} =-4.5V, I _D =-2A		117	140	
CHARGES, CAPACITANCES AND GATE RESISTANCE						
Input Capacitance	C _{ISS}	V _{GS} =0V, V _{DS} =-30V f=1MHz		315		pF
Output Capacitance	C _{OSS}			57		
Reverse Transfer Capacitance	C _{RSS}			4		
Gate Resistance	R _g	f=1MHZ		9.5		Ω
Total Gate Charge	Q _{G(TOT)}	V _{GS} =-10V, V _{DS} =-30V I _D =-2A		4.92		nC
Gate-to-Source Charge	Q _{GS}			0.97		
Gate-to-Drain Charge	Q _{GD}			0.72		
SWITCHING CHARACTERISTICS						
Turn-On Delay Time	t _{d(ON)}	V _{GS} =-10V, V _{DS} =-30V I _D =-2A, R _G =5Ω		6.8		ns
Rise Time	t _r			8		
Turn-Off Delay Time	t _{d(OFF)}			16		
Fall Time	t _f			4		
BODY DIODE CHARACTERISTICS						
Forward Voltage	V _{SD}	V _{GS} =0V, I _S =-3A			1.2	V

7. Typical Characteristic



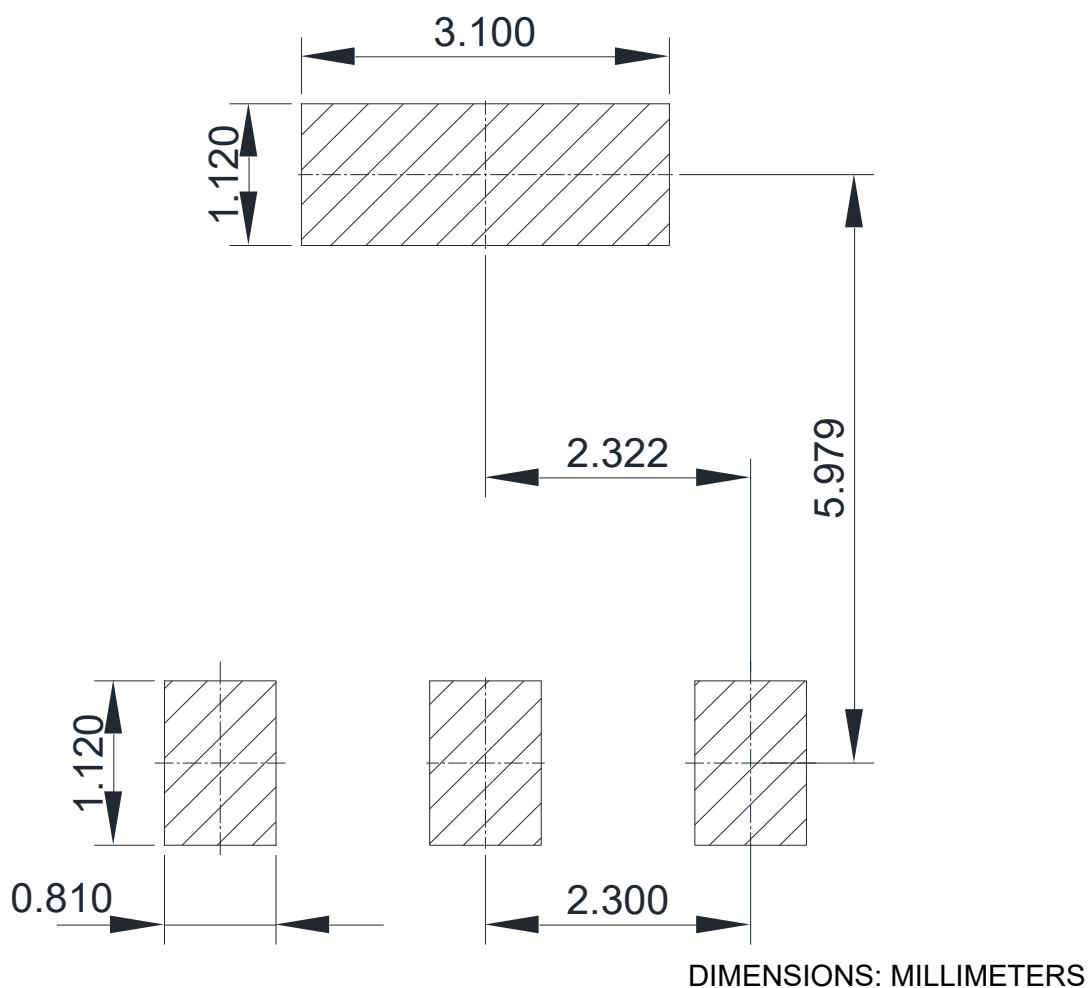
8. Dimension (SOT-223)

POD(J)



编号	尺寸 (mm)		
	Min	TYP	Max
A	1.550	1.600	1.650
A1	0.770	0.800	0.830
A2	0.000	0.050	0.100
D	6.300	6.350	6.400
E	3.450	3.500	3.550
E1	6.800	6.900	7.070
b1	2.950	3.000	3.050
b2	0.660	0.710	0.760
e	2.250	2.300	2.350
c	0.200	0.250	0.300
θ1	13° TYP		
θ2	0°	--	7°

9. Recommended Soldering Footprint



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